011751

54/7489

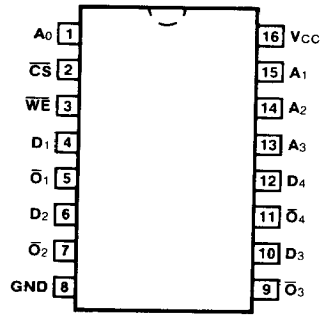
011749

54LS/74LS89

64-BIT RANDOM ACCESS MEMORY

(With Open-Collector Outputs)

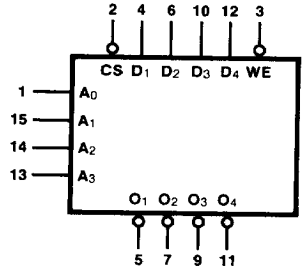
CONNECTION DIAGRAM
PINOUT A



DESCRIPTION — The '89 a high speed, low power 64-bit Random Access Memory organized as a 16-word by 4-bit array. Address inputs are buffered to minimize loading, and addresses are fully decoded on-chip. Outputs are open-collector type and are in the off (HIGH) state when both the Chip Select ($\overline{CS}$) and Write Enable ($\overline{WE}$) are HIGH. For all other combinations of $\overline{CS}$ and $\overline{WE}$ the outputs are active, presenting the complement of either the stored data (READ mode) or the information present on the D inputs.

- **OPEN-COLLECTOR OUTPUTS FOR WIRED-AND APPLICATIONS**
- **BUFFERED INPUTS MINIMIZE LOADING**
- **ADDRESS DECODING ON-CHIP**
- **DIODE CLAMPED INPUTS MINIMIZE RINGING**

LOGIC SYMBOL



VCC = Pin 16
GND = Pin 8

ORDERING CODE: See Section 9

PKGS	PIN OUT	COMMERCIAL GRADE: VCC = +5.0 V ±5%, TA = 0°C to +70°C	MILITARY GRADE: VCC = +5.0 V ±10%, TA = -55°C to +125°C	PKG TYPE
Plastic DIP (P)	A	7489PC, 74LS89PC		9B
Ceramic DIP (D)	A	7489DC, 74LS89DC	5489DM, 54LS89DM	7B
Flatpak (F)	A	7489FC, 74LS89FC	5489FM, 54LS89FM	4L

INPUT LOADING/FAN-OUT: See Section 3 for U.L. definitions

PIN NAMES	DESCRIPTION	54/74 (U.L.) HIGH/LOW	54/74LS (U.L.) HIGH/LOW
$A_0 - A_3$	Address Inputs	1.0/1.0	0.5/0.013
$\overline{CS}$	Chip Select Input (Active LOW)	1.0/1.0	0.5/0.013
$\overline{WE}$	Write Enable Input (Active LOW)	1.0/1.0	0.5/0.013
$D_1 - D_4$	Data Inputs	1.0/1.0	0.5/0.013
$\overline{O}_1 - \overline{O}_4$	Inverted Data Outputs	OC*/7.5	OC*/10 (5.0)

*OC — Open Collector

IMAGE UNAVAILABLE

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

SYMBOL	PARAMETER		54/74 Min	54/74 Max	54/74LS Min	54/74LS Max	UNITS	CONDITIONS	
I_{OH}	Output HIGH Current			20		20	μA	V_{CC} = Min, V_{OH} = 5.5 V	
V_{OL}	Output LOW Voltage			0.4			V	I_{OL} = 12 mA	V_{CC} = Min
				0.45				I_{OL} = 16 mA	
		XM, XC				0.4	V	I_{OL} = 8.0 mA	V_{CC} = Min
		XC				0.5		I_{OL} = 16 mA	
I_{CC}	Power Supply Current			105		40	mA	V_{CC} = Min, $\overline{CS}$ = Gnd	
C_O	Off-State Output Capacitance			4.0*		4.0*	pF	V_O = 2.4 V, f = 1 MHz	

AC CHARACTERISTICS: V_{CC} = +5.0 V, T_A = +25°C (See Section 3 for waveforms and load configurations)

SYMBOL	PARAMETER	54/74 C_L = 30 pF, R_L = 300 Ω Min	54/74 C_L = 30 pF, R_L = 300 Ω Max	54/74LS C_L = 15 pF, R_L = 2 kΩ Min	54/74LS C_L = 15 pF, R_L = 2 kΩ Max	UNITS	CONDITIONS
t_{PLH}	Propagation Delay $\overline{CS}$ to $\overline{O}_n$		50		10*	ns	Figs. 3-2, 3-5
t_{PHL}			50		10*		'89 has 600 Ω to Gnd
t_{PLH}	Propagation Delay A_n to $\overline{O}_n$		60		37*	ns	Figs. 3-2, 3-20
t_{PHL}			60		37*		'89 has 600 Ω to Gnd
t_{rec}	Recovery Time $\overline{WE}$ to $\overline{O}_n$		70		30*	ns	Figs. 3-2, 3-4, 3-5
							'89 has 600 Ω to Gnd

AC OPERATING REQUIREMENTS: V_{CC} = +5.0 V, T_A = +25°C

SYMBOL	PARAMETER	54/74 Min	54/74 Max	54/74LS Min	54/74LS Max	UNITS	CONDITIONS
t_s (H)	Setup Time HIGH or LOW D_n to $\overline{WE}$	40		25*		ns	Fig. 3-13
t_s (L)		40		25*			
t_s (H)	Setup Time HIGH or LOW A_n to $\overline{WE}$	0		10*		ns	Fig. 3-21
t_s (L)		0		10*			
t_h (H)	Hold Time HIGH or LOW D_n or A_n to $\overline{WE}$	5.0		0*		ns	Figs. 3-13, 3-21
t_h (L)		5.0		0*			
t_w (L)	$\overline{WE}$ Pulse Width LOW	40		25*		ns	Fig. 3-21

*Typical Value